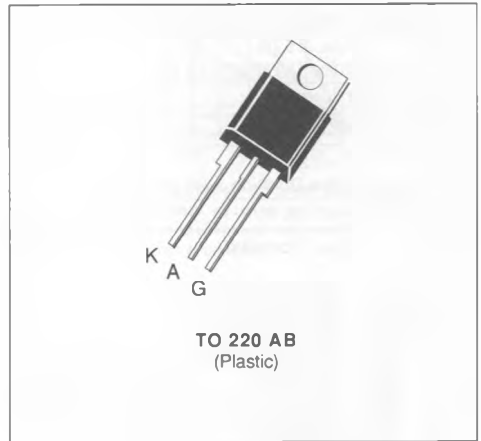




**THYRISTORS**

- GLASS PASSIVATED CHIP
- POSSIBILITY OF MOUNTING ON PRINTED CIRCUIT



**DESCRIPTION**

SCR's designed for motor control, heating controls, power supplies...

**ABSOLUTE RATINGS** (limiting values)

| Symbol             | Parameter   |                    | Value       | Unit       |
|--------------------|---|--------------------|-------------|------------|
| $I_{T(RMS)}$       | RMS on-state Current (1)  | $T_c = 85^\circ C$ | 20          | A          |
| $I_{T(AV)}$        | Mean on-state Current (1)   | $T_c = 85^\circ C$ | 13          | A          |
| $I_{TSM}$          | Non Repetitive Surge Peak on-state Current ( $T_j$ initial = $25^\circ C$ ) (2) | $t = 8.3$ ms       | 210         | A          |
|                    |   | $t = 10$ ms        | 200         |            |
| $I^2t$             | $I^2t$ Value for Fusing   | $t = 10$ ms        | 200         | $A^2s$     |
| $di/dt$            | Critical Rate of Rise of on-state Current (3)                                   |                    | 100         | $A/\mu s$  |
| $T_{stg}$<br>$T_j$ | Storage and Operating Junction Temperature Range                                |                    | - 40 to 125 | $^\circ C$ |
|                    |   |                    | - 40 to 125 | $^\circ C$ |

| Symbol                 | Parameter                             | TYN |     |     |     |     |     | Unit |
|------------------------|---------------------------------------|-----|-----|-----|-----|-----|-----|------|
|                        |                                       | 682 | 683 | 685 | 688 | 690 | 692 |      |
| $V_{DRM}$<br>$V_{RRM}$ | Repetitive Peak off-state Voltage (4) | 50  | 100 | 200 | 400 | 600 | 800 | V    |

- (1) Single phase circuit,  $180^\circ$  conduction angle.  
 (2) Half sine wave.  
 (3)  $I_G = 250$  mA  $di/dt = 1$  A/ $\mu s$ .  
 (4)  $T_j = 125^\circ C$ .

**THERMAL RESISTANCES**

| Symbol        | Parameter              | Value | Unit         |
|---------------|------------------------|-------|--------------|
| $R_{jh(j-c)}$ | Junction-case for D.C. | 2.5   | $^\circ C/W$ |
| $R_{jh(j-a)}$ | Junction-ambient       | 60    | $^\circ C/W$ |

**GATE CHARACTERISTICS** (maximum values)

$P_{GM} = 20 \text{ W}$  ( $t_p = 20 \mu\text{s}$ )

$I_{FGM} = 2 \text{ A}$  ( $t_p = 20 \mu\text{s}$ )

$V_{RGM} = 5 \text{ V}$

$P_{G(AV)} = 0.5 \text{ W}$

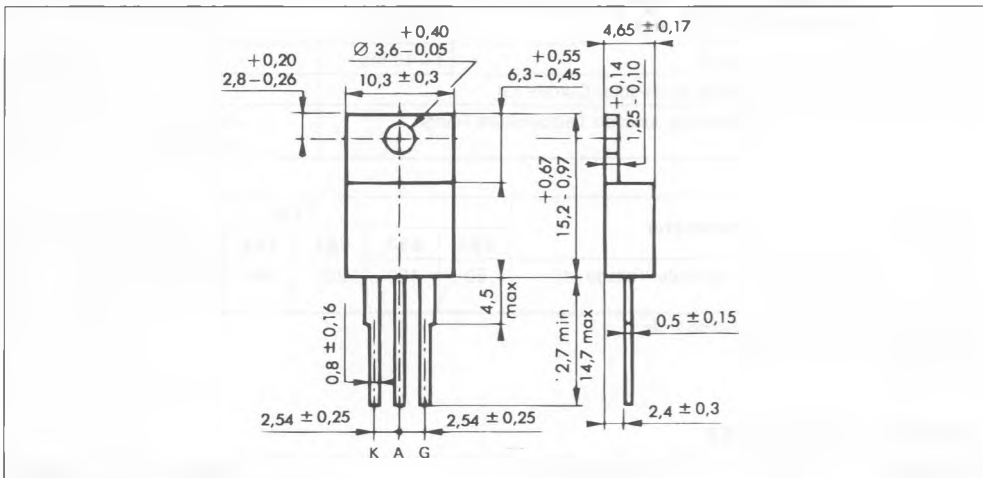
$V_{FGM} = 15 \text{ V}$  ( $t_p = 20 \mu\text{s}$ )

**ELECTRICAL CHARACTERISTICS**

| Symbol    | Test Conditions  |  |  | Min.                               | Typ. | Max. | Unit                   |
|-----------|--|--|--|------------------------------------|------|------|------------------------|
| $I_{GT}$  | $T_j = 25 \text{ }^\circ\text{C}$<br>Pulse Duration > 20 $\mu\text{s}$         | $V_D = 12 \text{ V}$                                       | $R_L = 33 \text{ } \Omega$                                 |                                    |      | 25   | mA                     |
| $V_{GT}$  | $T_j = 25 \text{ }^\circ\text{C}$<br>Pulse Duration > 20 $\mu\text{s}$         | $V_D = 12 \text{ V}$                                       | $R_L = 33 \text{ } \Omega$                                 |                                    |      | 1.5  | V                      |
| $V_{GD}$  | $T_j = 125 \text{ }^\circ\text{C}$   | $V_D = V_{DRM}$  | $R_L = 3.3 \text{ k}\Omega$                                | 0.2                                |      |      | V                      |
| $I_H$     | $T_j = 25 \text{ }^\circ\text{C}$  | $I_T = 100 \text{ mA}$                                     | Gate Open  |                                    |      | 40   | mA                     |
| $I_L$     | $T_j = 25 \text{ }^\circ\text{C}$<br>Pulse Duration > 20 $\mu\text{s}$         | $V_D = 12 \text{ V}$                                       | $I_G = 50 \text{ mA}$                                      |                                    | 70   |      | mA                     |
| $V_{TM}$  | $T_j = 25 \text{ }^\circ\text{C}$  | $I_{TM} = 50 \text{ A}$                                    | $t_p = 10 \text{ ms}$                                      |                                    |      | 1.4  | V                      |
| $I_{DRM}$ | $V_{DRM}$ Specified  |  |  | $T_j = 25 \text{ }^\circ\text{C}$  |      | 0.01 | mA                     |
|           |  |  |  | $T_j = 125 \text{ }^\circ\text{C}$ |      | 2    |                        |
| $I_{RRM}$ | $V_{RRM}$ Specified  |  |  | $T_j = 25 \text{ }^\circ\text{C}$  |      | 0.01 | mA                     |
|           |  |  |  | $T_j = 125 \text{ }^\circ\text{C}$ |      | 2    |                        |
| $t_{gt}$  | $T_j = 25 \text{ }^\circ\text{C}$<br>$I_G = 80 \text{ mA}$                     | $V_D = V_{DRM}$<br>$di_G/dt = 0.85 \text{ A}/\mu\text{s}$  | $I_T = 50 \text{ A}$                                       |                                    | 2    |      | $\mu\text{s}$          |
| $t_q$     | $T_j = 125 \text{ }^\circ\text{C}$<br>$V_D = 67 \% V_{DRM}$<br>Gate Open       | $I_T = 50 \text{ A}$<br>$di/dt = 30 \text{ A}/\mu\text{s}$ | $V_R = 25 \text{ V}$<br>$dv/dt = 50 \text{ V}/\mu\text{s}$ |                                    | 70   |      | $\mu\text{s}$          |
| $dv/dt^*$ | $T_j = 125 \text{ }^\circ\text{C}$<br>Linear Slope up to $V_D = 67 \% V_{DRM}$ | Gate Open  |  | 500                                |      |      | $\text{V}/\mu\text{s}$ |

\* For higher guaranteed values, please consult us.

**PACKAGE MECHANICAL DATA : TO 220 AB Plastic**



Cooling method : by conduction (method C)

Marking : type number

Weight : 2 g

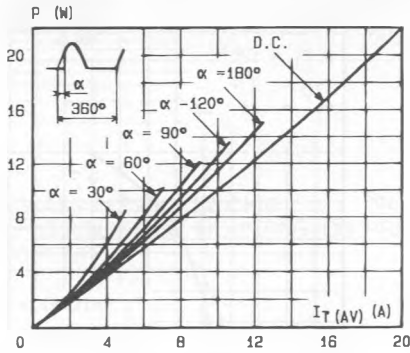


Fig. 1 - Maximum mean power dissipation versus mean on-state current.

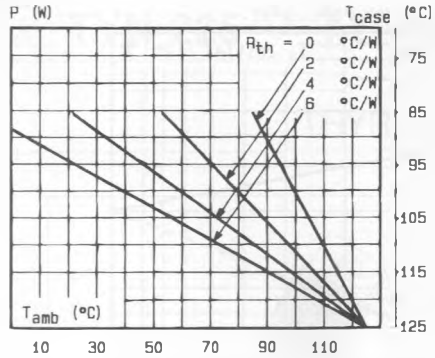


Fig. 2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact.

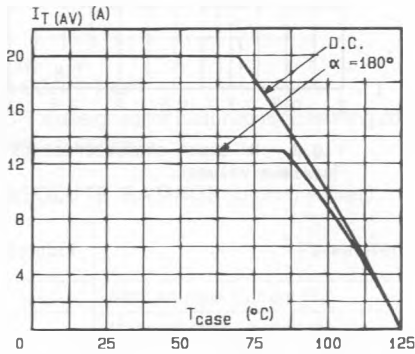


Fig. 3 - Mean on-state current versus case temperature.

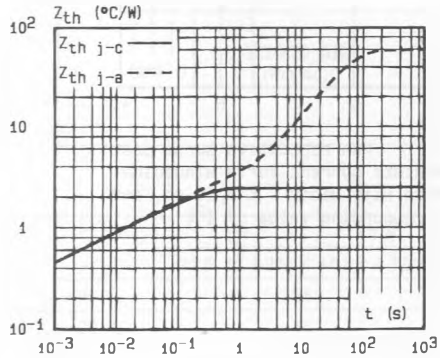


Fig. 4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

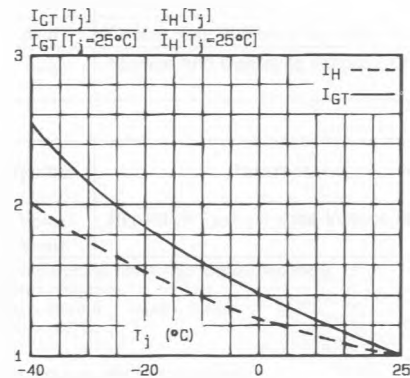


Fig. 5 - Relative variation of gate trigger current and holding current versus junction temperature.

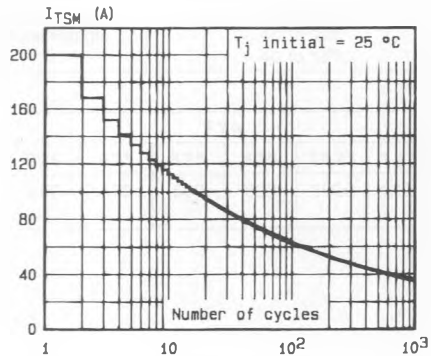


Fig. 6 - Non repetitive surge peak on-state current versus number of cycles.

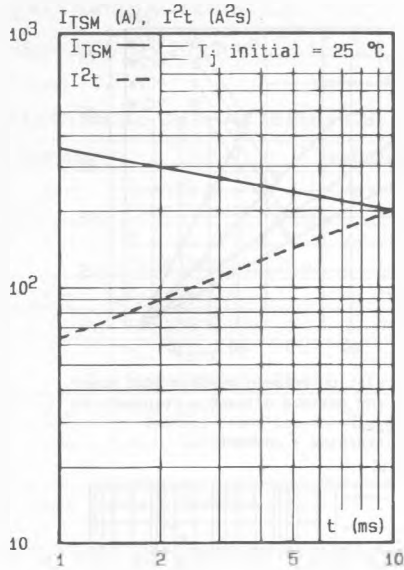


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

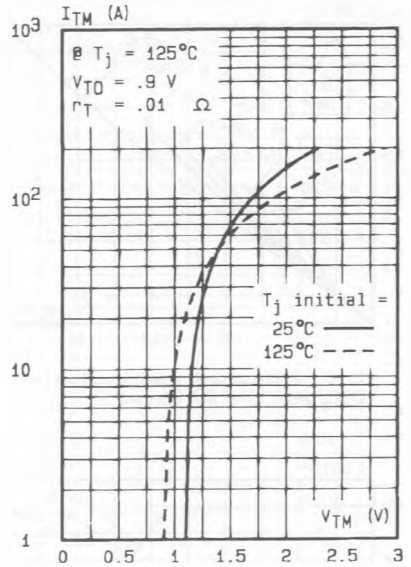


Fig.8 - Un-state characteristics (maximum values).